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#### October 2013

# FGA60N65SMD 650 V, 60 A Field Stop IGBT

#### Features

- Maximum Junction Temperature : T<sub>J</sub> = 175<sup>o</sup>C
- Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage:  $V_{CE(sat)} = 1.9 V(Typ.) @ I_{C} = 60 A$
- Fast Switching : E<sub>OFF</sub> = 7.5 uJ/A
- Tighten Parameter Distribution
- RoHS Compliant

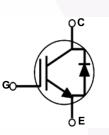
### Applications

• Solar Inverter, UPS, Welder, PFC, Telecom, ESS

# **General Description**

Using novel field stop IGBT technology, Fairchild's new series of field stop 2<sup>nd</sup> generation IGBTs offer the optimum performance for solar inverter, UPS, welder, telecom, ESS and PFC applications where low conduction and switching losses are essential.





#### **Absolute Maximum Ratings**

Symbol	Description		Ratings	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		650	V
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V
*GES	Transient Gate to Emitter Voltage		± 30	V
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25 <sup>o</sup> C	120	A
'C	Collector Current	@ T <sub>C</sub> = 100°C	60	A
I <sub>CM (1)</sub>	Pulsed Collector Current		180	A
I <sub>F</sub>	Diode Forward Current	@ T <sub>C</sub> = 25 <sup>o</sup> C	60	A
	Diode Forward Current	@ T <sub>C</sub> = 100°C	30	A
I <sub>FM (1)</sub>	Pulsed Diode Maximum Forward Current		180	А
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25 <sup>o</sup> C	600	W
	Maximum Power Dissipation @ $T_{C} = 100^{\circ}C$		300	W
TJ	Operating Junction Temperature		-55 to +175	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +175	
Τ <sub>L</sub>	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

# Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.25	°C/W
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case	-	1.1	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FGA60N65SMD	FGA60N65SMD	TO-3PN	-	-	30

# Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	toriotion					
		V 0V 1 2500 A	650	-		V
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	$V_{GE} = 0V, I_{C} = 250\mu A$	650	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_{J}}$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0V, I_C = 250 \mu A$	-	0.6	-	V/ºC
I <sub>CES</sub>	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$	-	-	250	μA
I <sub>GES</sub>	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$	-	-	±400	nA
On Charac	teristics					
V <sub>GE(th)</sub>	G-E Threshold Voltage	I <sub>C</sub> = 250μA, V <sub>CE</sub> = V <sub>GE</sub>	3.5	4.5	6.0	V
		$I_{\rm C} = 60$ A, $V_{\rm GE} = 15$ V	-	1.9	2.5	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage	$I_{C} = 60A, V_{GE} = 15V,$ $T_{C} = 175^{\circ}C$	-	2.1	-	V
Dynamic C	Characteristics		·			
C <sub>ies</sub>	Input Capacitance		-	2915	-	pF
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 30V$ , $V_{GE} = 0V$ ,	-	270	-	pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1MHz	-	85	-	pF
	Characteristics	1				
t <sub>d(on)</sub>	Turn-On Delay Time		T -	18	27	ns
t <sub>r</sub>	Rise Time	-	-	47	70	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>CC</sub> = 400V, I <sub>C</sub> = 60A,	-	104	146	ns
t <sub>f</sub>	Fall Time	$R_{G} = 3\Omega, V_{GE} = 15V,$	-	50	68	ns
Eon	Turn-On Switching Loss	Inductive Load, $T_C = 25^{\circ}C$	-	1.54	2.31	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.45	0.60	mJ
E <sub>ts</sub>	Total Switching Loss		-	1.99	2.91	mJ
t <sub>d(on)</sub>	Turn-On Delay Time		-	18	-	ns
t <sub>r</sub>	Rise Time	1	-	41	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>CC</sub> = 400V, I <sub>C</sub> = 60A,	-	115	-	ns
t <sub>f</sub>	Fall Time	$R_G = 3\Omega$ , $V_{GE} = 15V$ , Inductive Load, $T_C = 175^{\circ}C$	-	48	-	ns
E <sub>on</sub>	Turn-On Switching Loss		-	2.08	-	mJ
_	Turn-Off Switching Loss	1	-	0.78	-	mJ
E <sub>off</sub>	Turn-On Switching L035			00		

# Electrical Characteristics of the IGBT (Continued)

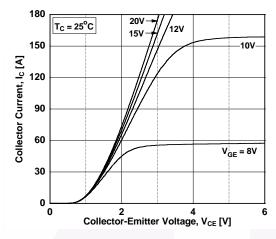
Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Qg	Total Gate Charge		-	189	284	nC
Q <sub>ge</sub>	Gate to Emitter Charge	V <sub>CE</sub> = 400V, I <sub>C</sub> = 60A, V <sub>GE</sub> = 15V	-	20	30	nC
Q <sub>gc</sub>	Gate to Collector Charge		-	91	137	nC

## Electrical Characteristics of the Diode T<sub>C</sub> = 25°C unless otherwise noted

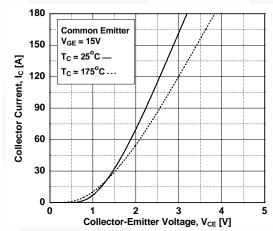
Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> = 30A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	2.1	2.6	V
VFM Diode i of ward voltage			T <sub>C</sub> = 175°C	-	1.7	-	
E <sub>rec</sub>	Reverse Recovery Energy		T <sub>C</sub> = 175 <sup>o</sup> C	-	127	-	uJ
t <sub>rr</sub>		I <sub>F</sub> =30A, dI <sub>F</sub> /dt = 200A/μs	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	47	-	ns
rr			T <sub>C</sub> = 175 <sup>o</sup> C	-	212	-	110
0	Q <sub>rr</sub> Diode Reverse Recovery Charge		$T_{\rm C} = 25^{\rm o}{\rm C}$	-	87	-	nC
αn			T <sub>C</sub> = 175 <sup>o</sup> C	-	933	-	110

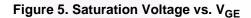
# **Typical Performance Characteristics**











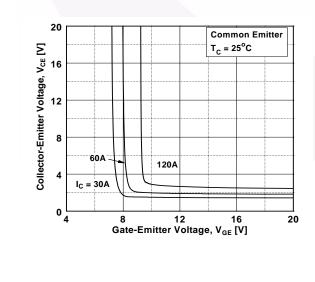
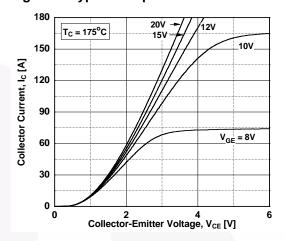
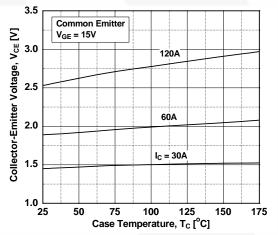
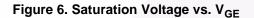


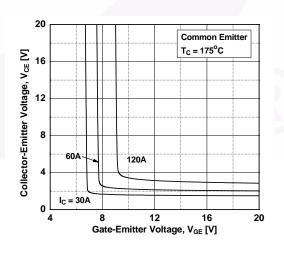
Figure 2. Typical Output Characteristics



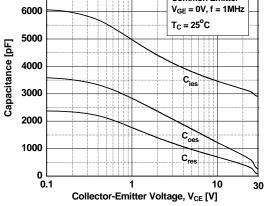








# Typical Performance Characteristics Figure 7. Capacitance Characteristics 7000 Common Emitter Yung OV for 1000





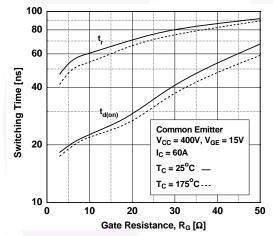


Figure 11. Switching Loss vs. Gate Resistance

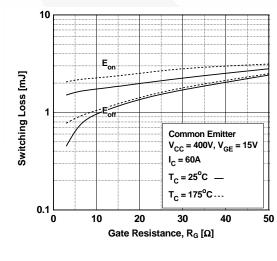
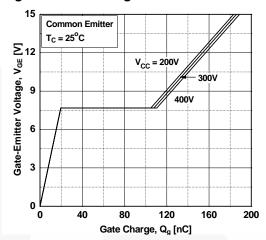
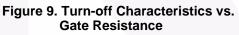
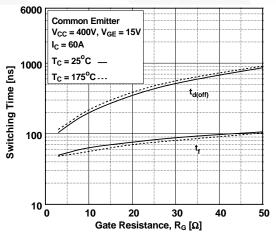
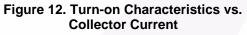


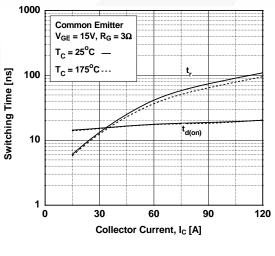
Figure 8. Gate charge Characteristics







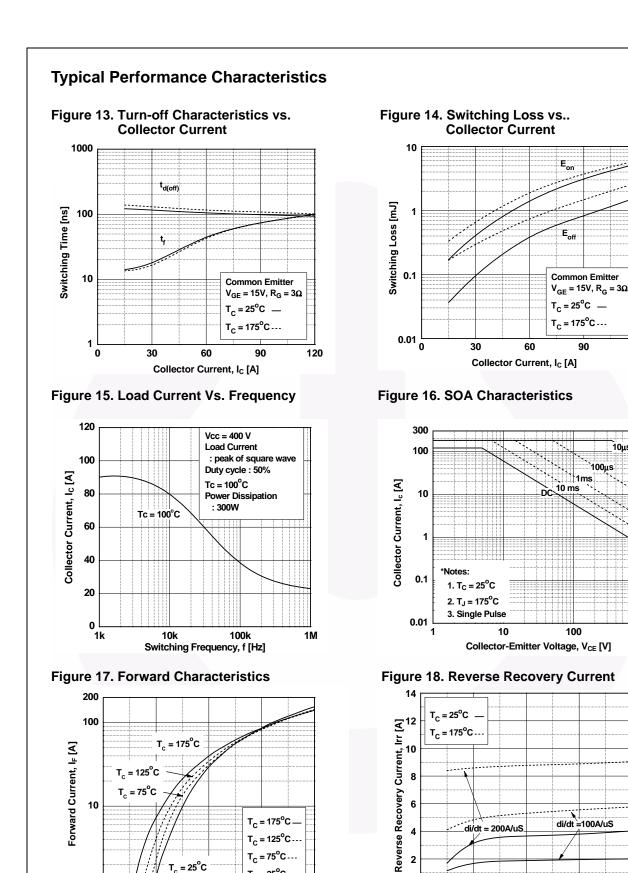




120

10µs

1000



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Forward Current, I<sub>F</sub> [A]

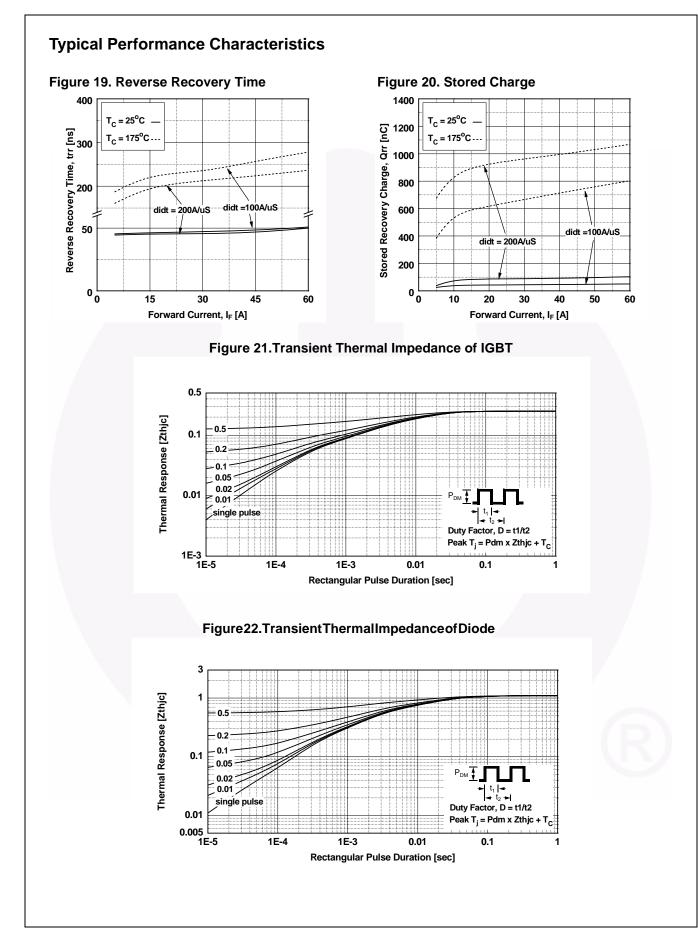
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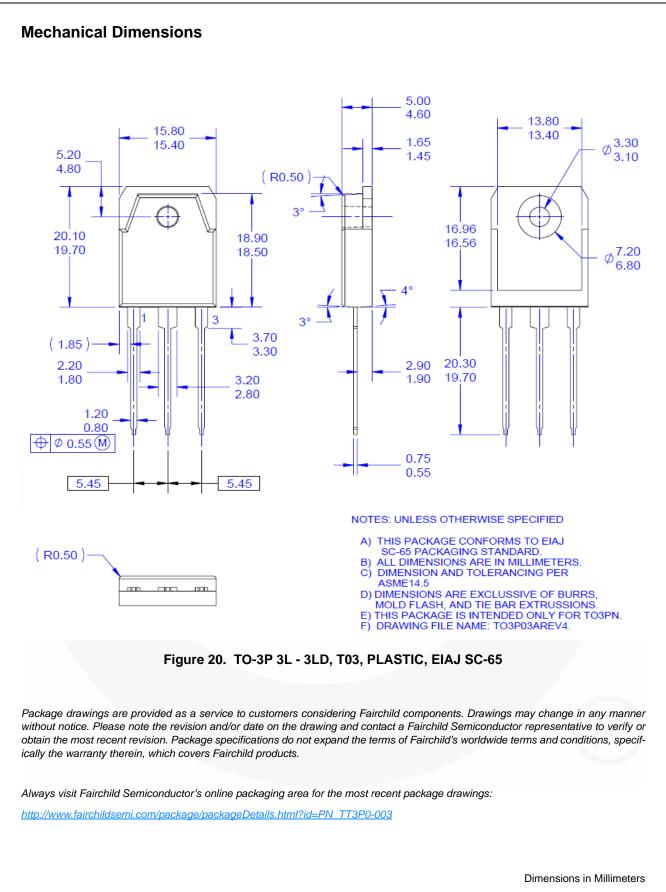
T<sub>C</sub> = 25°C

3

2

Forward Voltage, V<sub>F</sub> [V]





8



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650 V, 60 A Field Stop IGBT

GA60N65SMD ---

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